







**SN74AHCT1G125** 

SCLS3780 - AUGUST 1997 - REVISED OCTOBER 2023

# SN74AHCT1G125 Single Bus Buffer Gate With 3-State Output

#### 1 Features

- Operating Range of 4.5 V to 5.5 V
- Max t<sub>nd</sub> of 6 ns at 5 V
- Low Power Consumption, 10-µA Max I<sub>CC</sub>
- ±8-mA Output Drive at 5 V
- Inputs are TTL-Voltage Compatible
- Latch-Up Performance Exceeds 250 mA Per JESD 17

# 2 Applications

- Wireless Infrastructure
- Servers
- Power Infrastructure
- PCs/Notebooks
- **Programmable Logic Controllers**
- Tests and Measurements

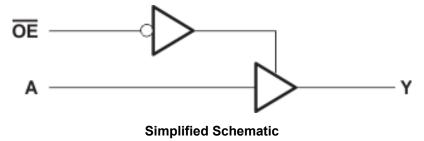
# 3 Description

The SN74AHCT1G125 device is a single bus buffer gate/line driver with 3-state output. The output is disabled when the output-enable (  $\overline{OE}$ ) input is high. When  $\overline{OE}$  is low, data is passed from the A input to the Y output.

#### **Package Information**

PART NUMBER	PACKAGE <sup>(1)</sup>	PACKAGE SIZE <sup>(2)</sup>
	DBV (SOT-23, 5)	2.8 mm x 2.8 mm
SN74AHCT1G125	DCK (SC-70, 5)	2.1 mm x 1.25 mm
	DRL (SOT-553, 5)	1.6 mm x 1.6 mm

- For all available packages, see the orderable addendum at the end of the data sheet.
- The package size (length × width) is a nominal value and includes pins, where applicable. 9



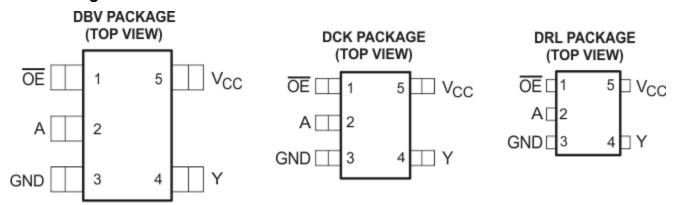


# **Table of Contents**

1 Features	1	8.2 Functional Block Diagram	8
2 Applications	1	8.3 Feature Description	<b>8</b>
3 Description	1	8.4 Device Functional Modes	<b>8</b>
4 Revision History		9 Application and Implementation	9
5 Pin Configuration and Functions		9.1 Application Information	
6 Specifications		9.2 Typical Application	
6.1 Absolute Maximum Ratings	4	9.3 Power Supply Recommendations	
6.2 ESD Ratings		9.4 Layout	
6.3 Recommended Operating Conditions		10 Device and Documentation Support	
6.4 Thermal Information		10.1 Receiving Notification of Documentation Upda	
6.5 Electrical Characteristics	5	10.2 Support Resources	
6.6 Switching Characteristics		10.3 Trademarks	
6.7 Operating Characteristics		10.4 Electrostatic Discharge Caution	
6.8 Typical Characteristics		10.5 Glossary	
7 Parameter Measurement Information		11 Mechanical, Packaging, and Orderable	
8 Detailed Description		Information	12
8.1 Overview			
4 Revision History			
Changes from Revision N (January 2016) to	Revision	O (October 2023)	Page
<ul> <li>Updated thermal values for DCK package fr</li> </ul>	om RθJA	cross-references throughout the document = 287.6 to 289.2, R0JC(top) = 97.7 to 205.8, R0J JC(bot) = N/A, all values in °C/W	B = 65
Changes from Revision M (December 2014)	to Revisi	on N (January 2016)	Page
		num Ratings section	



# **5 Pin Configuration and Functions**



See mechanical drawings for dimensions.

**Table 5-1. Pin Functions** 

	PIN		DESCRIPTION						
NO.	NAME	TYPE <sup>(1)</sup>	DESCRIPTION						
1	ŌĒ	I	Output Enable						
2	A	I	Input A						
3	GND	_	Ground Pin						
4	Y	0	Output Y						
5	V <sub>cc</sub>	_	Power Pin						

(1) Signal Types: I = Input, O = Output, I/O = Input or Output



# **6 Specifications**

# 6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)(1)

			MIN	MAX	UNIT
V <sub>CC</sub>	Supply voltage range	-0.5	7	V	
V <sub>I</sub> <sup>(2)</sup>	Input voltage range	-0.5	7	V	
V <sub>O</sub> (2)	Output voltage range	-0.5	V <sub>CC</sub> + 0.5	V	
I <sub>IK</sub>	Input clamp current	V <sub>1</sub> < 0		-20	mA
I <sub>OK</sub>	Output clamp current	$V_O < 0$ or $V_O > V_{CC}$		±20	mA
Io	Continuous output current	$V_O = 0$ to $V_{CC}$		±25	mA
	Continuous channel current through V <sub>CC</sub> or GND			±50	mA
T <sub>stg</sub>	Storage temperature range	-65	150	°C	
Tj	Junction temperature			150	°C

<sup>(1)</sup> Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under Section 6.3 is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

#### 6.2 ESD Ratings

			VALUE	UNIT
		Human body model (HBM), per ANSI/ESDA/JEDEC JS-001, all pins <sup>(1)</sup>	±1000	
V <sub>(ESD)</sub>	Electrostatic discharge	Charged device model (CDM), per JEDEC specification JESD22-C101, all pins <sup>(2)</sup>	±1500	V

<sup>(1)</sup> JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

#### 6.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)(1)

		MIN	MAX	UNIT
V <sub>CC</sub>	Supply voltage	4.5	5.5	V
V <sub>IH</sub>	High-level input voltage	2		V
V <sub>IL</sub>	Low-level input voltage		0.8	V
VI	Input voltage	0	5.5	V
Vo	Output voltage	0	V <sub>CC</sub>	V
I <sub>OH</sub>	High-level output current		-8	mA
I <sub>OL</sub>	Low-level output current		8	mA
Δt/Δν	Input transition rise or fall rate		20	ns/V
T <sub>A</sub>	Operating free-air temperature	-40	125	°C

<sup>(1)</sup> All unused inputs of the device must be held at V<sub>CC</sub> or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs (SCBA004).

<sup>2)</sup> The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

<sup>2)</sup> JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.



#### **6.4 Thermal Information**

		:	SN74AHCT1G12	5	
	THERMAL METRIC <sup>(1)</sup>	DBV	DCK	DRL	UNIT
			5 PINS		
$R_{\theta JA}$	Junction-to-ambient thermal resistance	231.3	289.2	328.7	
R <sub>0JC(top)</sub>	Junction-to-case (top) thermal resistance	119.9	205.8	105.1	
$R_{\theta JB}$	Junction-to-board thermal resistance	60.6	176.2	150.3	°C/W
ΨЈТ	Junction-to-top characterization parameter	17.8	117.6	6.9	- C/VV
$\Psi_{JB}$	Junction-to-board characterization parameter	60.1	175.1	148.4	
$R_{\theta JC(bot)}$	Junction-to-case (bot) thermal resistance	N/A	N/A	N/A	

<sup>(1)</sup> For more information about traditional and new thermal metrics, see the IC Package Thermal Metrics application report (SPRA953).

#### 6.5 Electrical Characteristics

over recommended operating free-air temperature range (unless otherwise noted)

	PARAMETER	TEST	V <sub>cc</sub>	T	_ = 25°C		-40°C to	85°C	–40°0 125°		UNIT
		CONDITIONS		MIN	TYP	MAX	MIN	MAX	MIN	MAX	
V <sub>OH</sub>	High level output voltage	I <sub>OH</sub> = -50 μA	4.5 V	4.4	4.5		4.4		4.4		V
<b>У</b> ОН	riigirievel output voitage	I <sub>OH</sub> = -8 mA	4.5 V	3.94			3.8		3.8		v
V	Lew level output voltage	I <sub>OL</sub> = 50 μA	4.5 V			0.1		0.1		0.1	V
V <sub>OL</sub>	Low level output voltage	I <sub>OL</sub> = 8 mA	4.5 V			0.36		0.44		0.44	v
I	Input leakage current	V <sub>I</sub> = 5.5 V or GND	0 V to 5.5 V			±0.1		±1		±1	μA
I <sub>OZ</sub>	Off-State (High-Impedance State) Output Current (of a 3-State Output)	V <sub>O</sub> = V <sub>CC</sub> or GND	5.5 V			±0.25		±2.5		±2.5	μA
I <sub>CC</sub>	Supply current	$V_I = V_{CC}$ or GND, $I_O = 0$	5.5 V			1		10		10	μΑ
Δl <sub>CC</sub> (1)	Supply-current change	One input at 3.4 V, Other input at V <sub>CC</sub> or GND	5.5 V			1.35		1.5		1.5	mA
Ci	Input capacitance	V <sub>I</sub> = V <sub>CC</sub> or GND	5 V		4	10		10		10	pF
Co	Output capacitance	V <sub>O</sub> = V <sub>CC</sub> or GND	5 V		10						pF

<sup>(1)</sup> This is the increase in supply current for each input at one of the specified TTL voltage levels, rather than 0 V or  $V_{CC}$ .



# **6.6 Switching Characteristics**

over recommended operating free-air temperature range,  $V_{CC}$  = 5 V ± 0.5 V (unless otherwise noted) (see Load Circuit and Voltage Waveforms)

DADAMETED	FROM	то	LOAD	TA	= 25°C		-40°C to	85°C	-40°C to	125°C	LINUT
PARAMETER	(INPUT)	(OUTPUT)	CAPACITANCE	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNIT
t <sub>PLH</sub>	A	Y	C = 15 pE		3.8	5.5	1	6.5	1	7	no
t <sub>PHL</sub>	A	Ī	C <sub>L</sub> = 15 pF		3.8	5.5	1	6.5	1	7	ns
t <sub>PZH</sub>	ŌĒ	Y	C <sub>L</sub> = 15 pF		3.6	5.1	1	6	1	6.5	ns
t <sub>PZL</sub>		ľ	OL = 13 pi		3.6	5.1	1	6	1	6.5	115
t <sub>PHZ</sub>	ŌĒ	Υ	C <sub>1</sub> = 15 pF		4.6	6.8	1	8	1	8.5	ns
t <sub>PLZ</sub>		'	OL = 13 pi		4.6	6.8	1	8	1	8.5	
t <sub>PLH</sub>	А	Y	C <sub>1</sub> = 50 pF		5.3	7.5	1	8.5	1	9.5	ns
t <sub>PHL</sub>	A	I	CL = 30 pr		5.3	7.5	1	8.5	1	9.5	115
t <sub>PZH</sub>	ŌĒ	Υ	C. = 50 pE		5.1	7.1	1	8	1	9	ne
t <sub>PZL</sub>	OL	ı	C <sub>L</sub> = 50 pF		5.1	7.1	1	8	1	9	ns
t <sub>PHZ</sub>	ŌĒ	Y	C <sub>L</sub> = 50 pF		6.1	8.8	1	10	1	11	ns
t <sub>PLZ</sub>	OE .	r	OL - 30 PF		6.1	8.8	1	10	1	11	115

# **6.7 Operating Characteristics**

 $V_{CC}$  = 5 V,  $T_A$  = 25°C

	PARAMETER	TEST CO	ONDITIONS	TYP	UNIT
C <sub>pd</sub>	Power dissipation capacitance	No load,	f = 1 MHz	14	pF

# **6.8 Typical Characteristics**

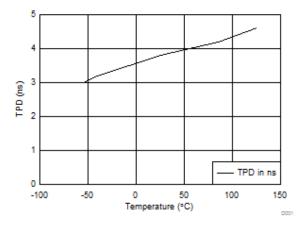
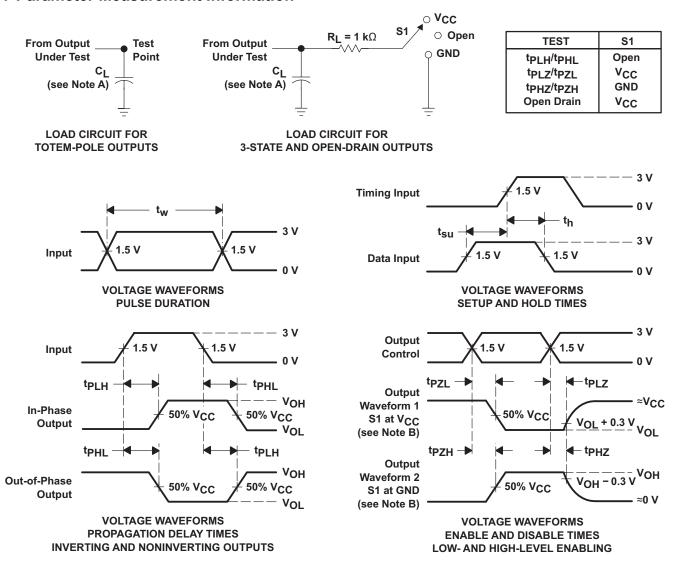


Figure 6-1. TPD vs Temperature



#### 7 Parameter Measurement Information



NOTES: A.  $C_L$  includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  1 MHz,  $Z_O$  = 50  $\Omega$ ,  $t_f \leq$  3 ns.  $t_f \leq$  3 ns.
- D. The outputs are measured one at a time, with one input transition per measurement.
- E. All parameters and waveforms are not applicable to all devices.

Figure 7-1. Load Circuit and Voltage Waveforms



#### **8 Detailed Description**

#### 8.1 Overview

The SN74AHCT1G125 device is a single bus buffer gate/line driver with 3-state output. The output is disabled when the output-enable ( $\overline{OE}$ ) input is high. When  $\overline{OE}$  is low, data is passed from the A input to the Y output.

To ensure the high-impedance state during power up or power down,  $\overline{OE}$  should be tied to  $V_{CC}$  through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

#### 8.2 Functional Block Diagram

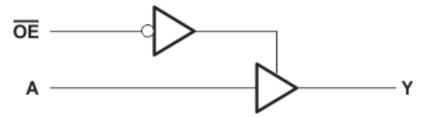


Figure 8-1. Logic Diagram (Positive Logic)

#### 8.3 Feature Description

- TTL inputs
  - Lowered switching threshold allows up translation 3.3 V to 5 V
- Slow edges reduce output ringing

#### 8.4 Device Functional Modes

**Table 8-1. Function Table** 

INPU	TS <sup>(1)</sup>	OUTPUT <sup>(2)</sup>
ŌĒ	Α	Y
L	Н	Н
L	L	L
Н	Χ	Z

- (1) H = High Voltage Level, L = Low Voltage Level, X = Don't Care
- (2) H = Driving High, L = Driving Low, Z = High Impedance State

# 9 Application and Implementation

#### Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

#### 9.1 Application Information

The SN74AHCT1G125 is a low-drive CMOS device that can be used for a multitude of bus interface type applications where output ringing is a concern. The low drive and slow edge rates will minimize overshoot and undershoot on the outputs. The input switching levels have been lowered to accommodate TTL inputs of 0.8 V  $V_{IL}$  and 2V  $V_{IH}$ . This feature makes it Ideal for translating up from 3.3 V to 5 V. Figure 9-1 shows this type of translation.

#### 9.2 Typical Application

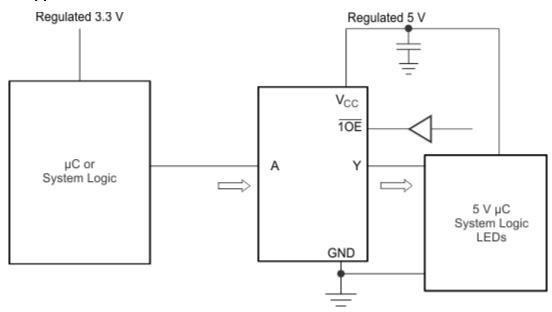


Figure 9-1. Typical Application Schematic

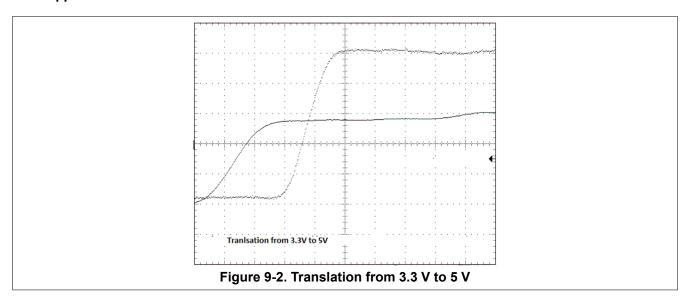
#### 9.2.1 Design Requirements

This device uses CMOS technology and has balanced output drive. Care should be taken to avoid bus contention because it can drive currents that would exceed maximum limits. The high drive will also create fast edges into light loads, so routing and load conditions should be considered to prevent ringing.

#### 9.2.2 Detailed Design Procedure

- 1. Recommended Input Conditions
  - For rise time and fall time specifications, see  $\Delta t/\Delta V$  in the Section 6.3 table.
  - For specified High and low levels, see V<sub>IH</sub> and V<sub>II</sub> in the Section 6.3 table.
  - Inputs are overvoltage tolerant allowing them to go as high as 5.5 V at any valid V<sub>CC</sub>.
- 2. Recommend Output Conditions
  - Load currents should not exceed 25 mA per output and 50 mA total for the part.
  - Outputs should not be pulled above V<sub>CC</sub>.

#### 9.2.3 Application Curves



#### 9.3 Power Supply Recommendations

The power supply can be any voltage between the MIN and MAX supply voltage rating located in the Section 6.3 table.

Each  $V_{CC}$  pin should have a good bypass capacitor to prevent power disturbance. For devices with a single supply, 0.1  $\mu$ F is recommended. If there are multiple  $V_{CC}$  pins, 0.01  $\mu$ F or 0.022  $\mu$ F is recommended for each power pin. It is acceptable to parallel multiple bypass caps to reject different frequencies of noise. A 0.1  $\mu$ F and 1  $\mu$ F are commonly used in parallel. The bypass capacitor should be installed as close to the power pin as possible for best results.

#### 9.4 Layout

#### 9.4.1 Layout Guidelines

When using multiple bit logic devices, inputs should not float. In many cases, functions or parts of functions of digital logic devices are unused. Some examples are when only two inputs of a triple-input AND gate are used, or when only 3 of the 4-buffer gates are used. Such input pins should not be left unconnected because the undefined voltages at the outside connections result in undefined operational states.

Specified in Figure 9-3 are rules that must be observed under all circumstances. All unused inputs of digital logic devices must be connected to a high or low bias to prevent them from floating. The logic level that should be applied to any particular unused input depends on the function of the device. Generally they will be tied to GND or  $V_{CC}$ , whichever makes more sense or is more convenient. It is acceptable to float outputs unless the part is a transceiver. If the transceiver has an output enable pin, it will disable the outputs section of the part when asserted. This will not disable the input section of the I/Os so they also cannot float when disabled.



# 9.4.1.1 Layout Example

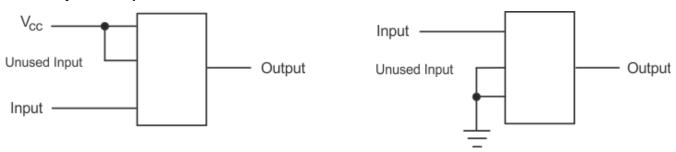


Figure 9-3. Layout Diagram



# 10 Device and Documentation Support

## 10.1 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. Click on *Subscribe to updates* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

#### 10.2 Support Resources

TI E2E<sup>™</sup> support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

Linked content is provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

#### 10.3 Trademarks

TI E2E™ is a trademark of Texas Instruments.

All trademarks are the property of their respective owners.

#### 10.4 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

#### 10.5 Glossary

TI Glossary

This glossary lists and explains terms, acronyms, and definitions.

#### 11 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

Submit Document Feedback

Copyright © 2023 Texas Instruments Incorporated

www.ti.com 2-Nov-2023

#### **PACKAGING INFORMATION**

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
74AHCT1G125DBVRG4	ACTIVE	SOT-23	DBV	5	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	B25G	Samples
74AHCT1G125DBVTG4	ACTIVE	SOT-23	DBV	5	250	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	B25G	Samples
74AHCT1G125DCKRG4	ACTIVE	SC70	DCK	5	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	ВМЗ	Samples
74AHCT1G125DCKTE4	ACTIVE	SC70	DCK	5	250	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	ВМЗ	Samples
74AHCT1G125DCKTG4	ACTIVE	SC70	DCK	5	250	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	BM3	Samples
SN74AHCT1G125DBVR	ACTIVE	SOT-23	DBV	5	3000	RoHS & Green	NIPDAU   SN	Level-1-260C-UNLIM	-40 to 125	(B253, B25G, B25J, B25L, B25S)	Samples
SN74AHCT1G125DCK3	ACTIVE	SC70	DCK	5	3000	RoHS & Non-Green	SNBI	Level-1-260C-UNLIM	-40 to 85	ВМҮ	Samples
SN74AHCT1G125DCKR	ACTIVE	SC70	DCK	5	3000	RoHS & Green	NIPDAU   SN	Level-1-260C-UNLIM	-40 to 125	(BM3, BMG, BMJ, BM L, BMS)	Samples
SN74AHCT1G125DCKT	LIFEBUY	SC70	DCK	5	250	RoHS & Green	NIPDAU   SN	Level-1-260C-UNLIM	-40 to 125	(BM3, BMG, BMJ, BM L, BMS)	
SN74AHCT1G125DRLR	ACTIVE	SOT-5X3	DRL	5	4000	RoHS & Green	NIPDAU   NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	(BMB, BMS)	Samples

<sup>(1)</sup> The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

<sup>(2)</sup> RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

<sup>(3)</sup> MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

#### PACKAGE OPTION ADDENDUM



www.ti.com 2-Nov-2023

- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

#### OTHER QUALIFIED VERSIONS OF SN74AHCT1G125:

Automotive : SN74AHCT1G125-Q1

NOTE: Qualified Version Definitions:

Automotive - Q100 devices qualified for high-reliability automotive applications targeting zero defects



www.ti.com 5-Oct-2023

#### TAPE AND REEL INFORMATION



# TAPE DIMENSIONS WHO WE PI WHO WE BO W Cavity AO AO Cavity C

	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

#### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



#### \*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
74AHCT1G125DBVRG4	SOT-23	DBV	5	3000	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
74AHCT1G125DBVTG4	SOT-23	DBV	5	250	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
74AHCT1G125DCKRG4	SC70	DCK	5	3000	178.0	9.2	2.4	2.4	1.22	4.0	8.0	Q3
74AHCT1G125DCKTG4	SC70	DCK	5	250	178.0	9.2	2.4	2.4	1.22	4.0	8.0	Q3
SN74AHCT1G125DBVR	SOT-23	DBV	5	3000	178.0	9.0	3.3	3.2	1.4	4.0	8.0	Q3
SN74AHCT1G125DBVR	SOT-23	DBV	5	3000	180.0	8.4	3.23	3.17	1.37	4.0	8.0	Q3
SN74AHCT1G125DCKR	SC70	DCK	5	3000	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3
SN74AHCT1G125DCKT	SC70	DCK	5	250	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3
SN74AHCT1G125DCKT	SC70	DCK	5	250	178.0	9.2	2.4	2.4	1.22	4.0	8.0	Q3
SN74AHCT1G125DCKT	SC70	DCK	5	250	180.0	8.4	2.47	2.3	1.25	4.0	8.0	Q3
SN74AHCT1G125DRLR	SOT-5X3	DRL	5	4000	180.0	8.4	1.98	1.78	0.69	4.0	8.0	Q3



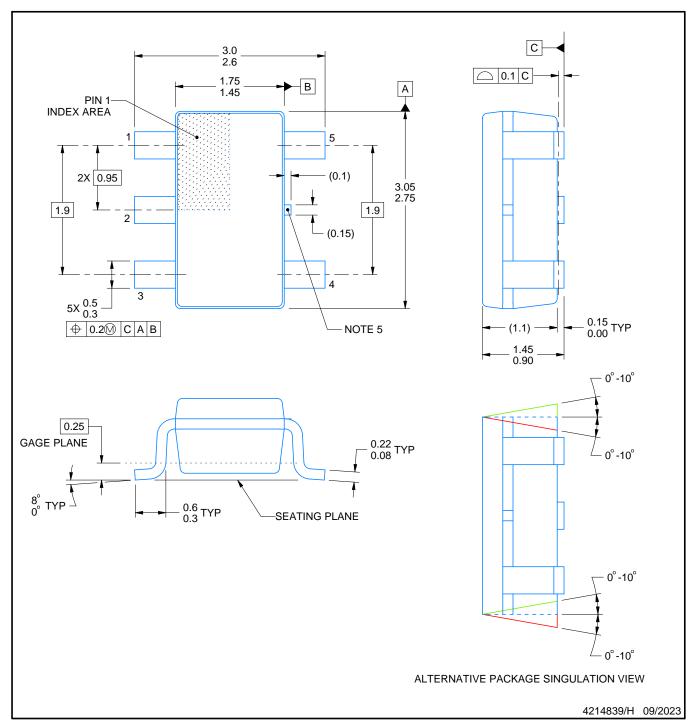
www.ti.com 5-Oct-2023



#### \*All dimensions are nominal

All differsions are normal										
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)			
74AHCT1G125DBVRG4	SOT-23	DBV	5	3000	180.0	180.0	18.0			
74AHCT1G125DBVTG4	SOT-23	DBV	5	250	180.0	180.0	18.0			
74AHCT1G125DCKRG4	SC70	DCK	5	3000	180.0	180.0	18.0			
74AHCT1G125DCKTG4	SC70	DCK	5	250	180.0	180.0	18.0			
SN74AHCT1G125DBVR	SOT-23	DBV	5	3000	180.0	180.0	18.0			
SN74AHCT1G125DBVR	SOT-23	DBV	5	3000	202.0	201.0	28.0			
SN74AHCT1G125DCKR	SC70	DCK	5	3000	180.0	180.0	18.0			
SN74AHCT1G125DCKT	SC70	DCK	5	250	180.0	180.0	18.0			
SN74AHCT1G125DCKT	SC70	DCK	5	250	180.0	180.0	18.0			
SN74AHCT1G125DCKT	SC70	DCK	5	250	202.0	201.0	28.0			
SN74AHCT1G125DRLR	SOT-5X3	DRL	5	4000	202.0	201.0	28.0			



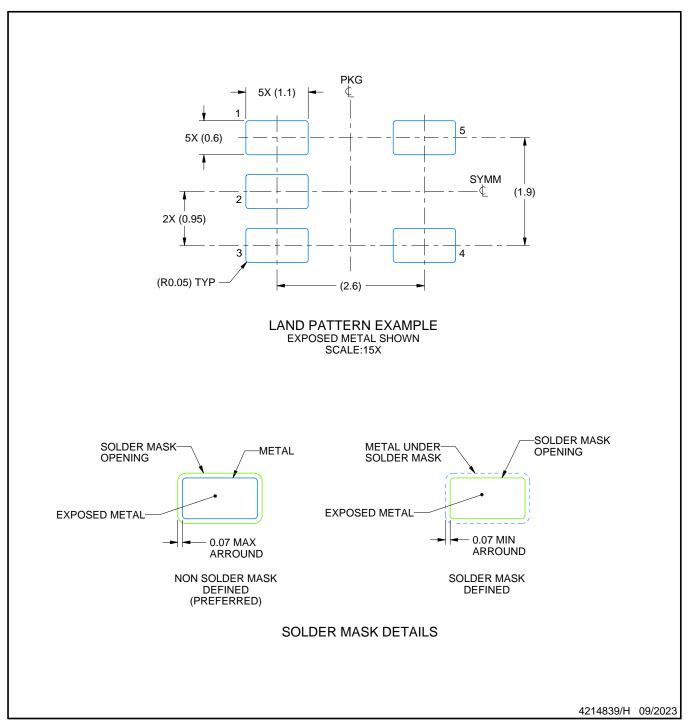


#### NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
  2. This drawing is subject to change without notice.
  3. Refernce JEDEC MO-178.

- 4. Body dimensions do not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.25 mm per side.
- 5. Support pin may differ or may not be present.





NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.





NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.





PLASTIC SMALL OUTLINE



#### NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

  2. This drawing is subject to change without notice.

  3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
  4. Reference JEDEC registration MO-293 Variation UAAD-1



PLASTIC SMALL OUTLINE

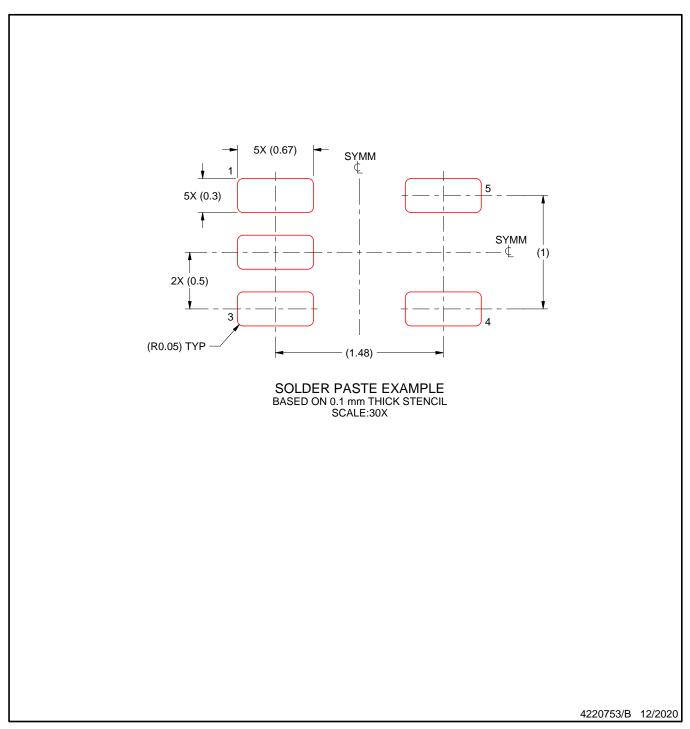


NOTES: (continued)

- 5. Publication IPC-7351 may have alternate designs.
- 6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



PLASTIC SMALL OUTLINE

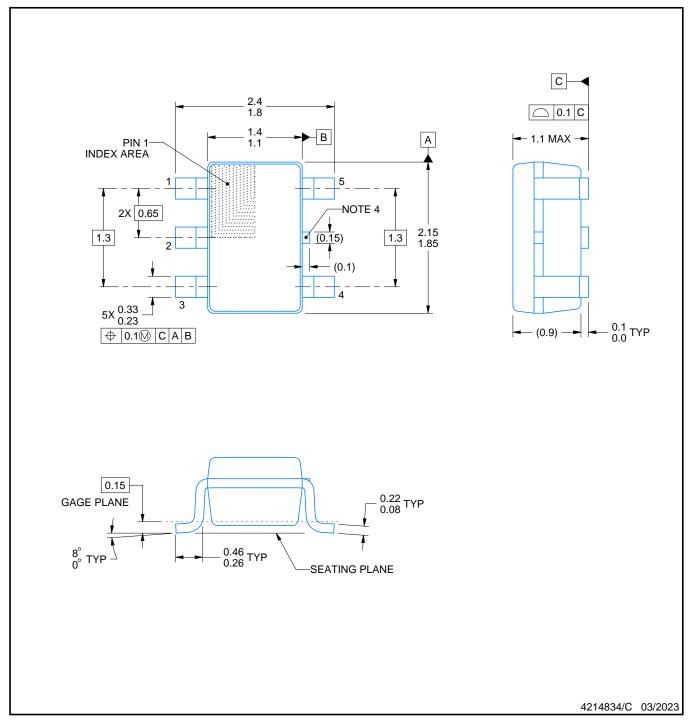


NOTES: (continued)

- 7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 8. Board assembly site may have different recommendations for stencil design.







#### NOTES:

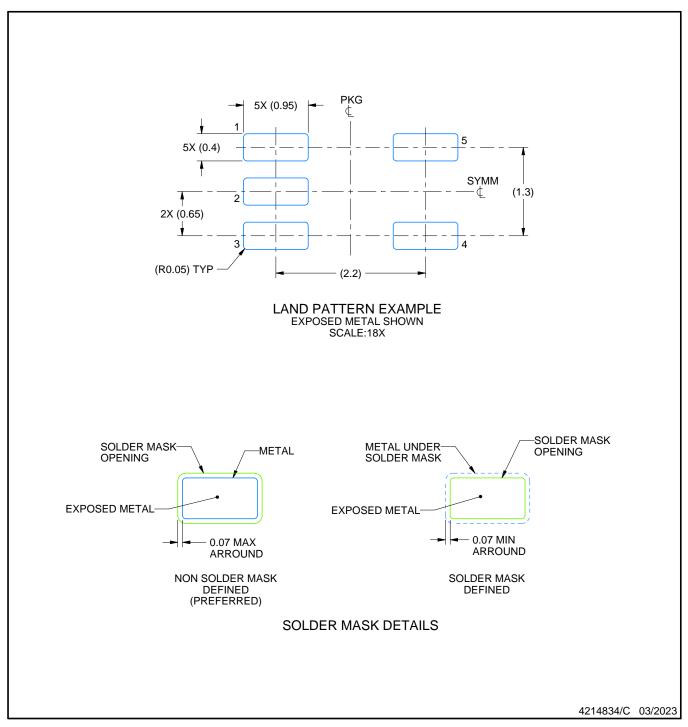
- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

  2. This drawing is subject to change without notice.

  3. Reference JEDEC MO-203.

- 4. Support pin may differ or may not be present.

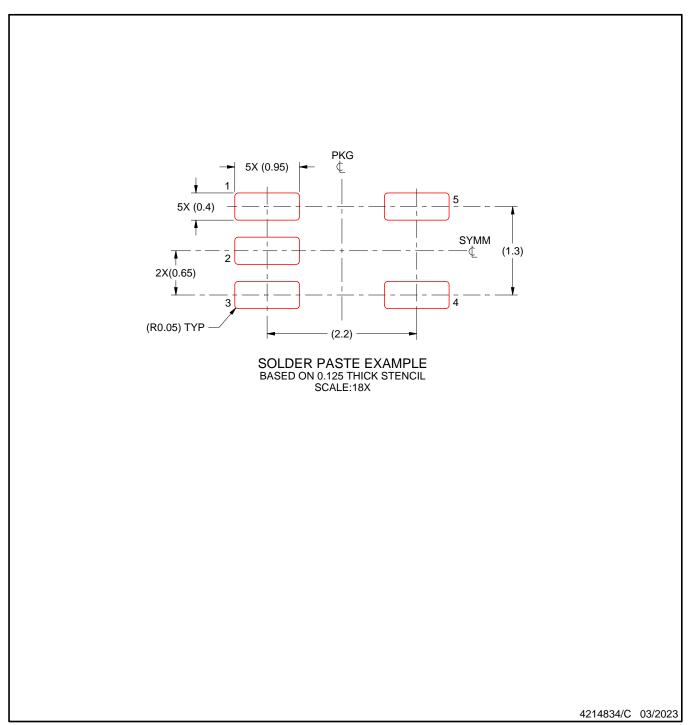




NOTES: (continued)

4. Publication IPC-7351 may have alternate designs.5. Solder mask tolerances between and around signal pads can vary based on board fabrication site.





NOTES: (continued)

- 6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 7. Board assembly site may have different recommendations for stencil design.



#### IMPORTANT NOTICE AND DISCLAIMER

TI PROVIDES TECHNICAL AND RELIABILITY DATA (INCLUDING DATA SHEETS), DESIGN RESOURCES (INCLUDING REFERENCE DESIGNS), APPLICATION OR OTHER DESIGN ADVICE, WEB TOOLS, SAFETY INFORMATION, AND OTHER RESOURCES "AS IS" AND WITH ALL FAULTS, AND DISCLAIMS ALL WARRANTIES, EXPRESS AND IMPLIED, INCLUDING WITHOUT LIMITATION ANY IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE OR NON-INFRINGEMENT OF THIRD PARTY INTELLECTUAL PROPERTY RIGHTS.

These resources are intended for skilled developers designing with TI products. You are solely responsible for (1) selecting the appropriate TI products for your application, (2) designing, validating and testing your application, and (3) ensuring your application meets applicable standards, and any other safety, security, regulatory or other requirements.

These resources are subject to change without notice. TI grants you permission to use these resources only for development of an application that uses the TI products described in the resource. Other reproduction and display of these resources is prohibited. No license is granted to any other TI intellectual property right or to any third party intellectual property right. TI disclaims responsibility for, and you will fully indemnify TI and its representatives against, any claims, damages, costs, losses, and liabilities arising out of your use of these resources.

TI's products are provided subject to TI's Terms of Sale or other applicable terms available either on ti.com or provided in conjunction with such TI products. TI's provision of these resources does not expand or otherwise alter TI's applicable warranties or warranty disclaimers for TI products.

TI objects to and rejects any additional or different terms you may have proposed.

Mailing Address: Texas Instruments, Post Office Box 655303, Dallas, Texas 75265 Copyright © 2023, Texas Instruments Incorporated

# 单击下面可查看定价,库存,交付和生命周期等信息

# >>TI (德州仪器)